- Function and Pinout Compatible With FCT and F Logic
- 25-Ω Output Series Resistors to Reduce Transmission-Line Reflection Noise
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- 12-mA Output Sink Current
 15-mA Output Source Current
- 3-State Outputs

(TOP VIEW) 20 🛮 V_{CC} T/R [19 N OE A₀ **[**]2 18 ∏ B₀ A₁ []3 17 🛮 B₁ A₂ 🛮 4 A₃ 🛮 5 16 **∏** B₂ A₄ [15 🛮 B₃ A₅ 14 ∏ B₄ A₆ 🛮 8 13 B₅ 12 🛮 B₆ A₇ **[]** 9 GND **1**10 11 B₇

P, Q, OR SO PACKAGE

description

The CY74FCT2245T contains eight noninverting, bidirectional buffers with 3-state outputs intended for bus-oriented applications. On-chip termination resistors at the outputs reduce system noise caused by reflections. For this reason, the CY74FCT2245T can replace the CY74FCT245T in an existing design. The CY74FCT2245T current-sinking capability is 12 mA at the A and B ports.

The transmit/receive (T/R) input determines the direction of data flow through the bidirectional transceiver. Transmit (active high) enables data from A ports to B ports; receive (active low) enables data from B ports to A ports. The output-enable (\overline{OE}) input, when high, disables both the A and B ports by putting them in the high-impedance state.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

TA	PACKAGE [†]		SPEED ORDERABLE (ns) PART NUMBER		TOP-SIDE MARKING	
	QSOP - Q	Tape and reel	4.1	CY74FCT2245CTQCT	FCT2245	
	SOIC - SO	Tube	4.1	CY74FCT2245CTSOC	FCT2245	
	3010 - 30	Tape and reel	4.1	CY74FCT2245CTSOCT	FC12245	
	DIP – P	Tube	4.6	CY74FCT2245ATPC	74FCT2245ATPC	
–40°C to 85°C	QSOP – Q	Tape and reel	4.6	CY74FCT2245ATQCT	FCT2245A	
-40 C to 65 C	SOIC - SO	Tube	4.6	CY74FCT2245ATSOC	FCT2245A	
	3010 - 30	Tape and reel	4.6	CY74FCT2245ATSOCT	FC12243A	
	QSOP - Q	Tape and reel	7.0	CY74FCT2245TQCT	FCT2245	
	SOIC - SO	Tube	7.0	CY74FCT2245TSOC	FCT2245	
	3010 - 80	Tape and reel	7.0	CY74FCT2245TSOCT	FU12240	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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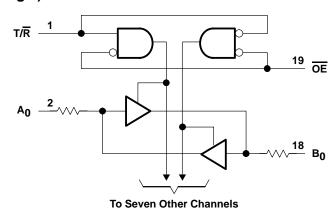


FUNCTION TABLE

INP	UTS	OUTPUT			
OE	T/R				
L	L	Bus B data to bus A			
L	Н	Bus A data to bus B			
Н	Χ	Z			

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

	-0.5 V to 7 V
DC input voltage range	
DC output voltage range	
DC output current (maximum sink current/pin)	
	P package 69°C/W
	Q package 68°C/W
	SO package 58°C/W
Ambient temperature range with power applied,	T _A –65°C to 135°C
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
٧ıH	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
loh	High-level output current			-15	mA
l _{OL}	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at $V_{\hbox{\footnotesize{CC}}}$ or GND to ensure proper device operation.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP†	MAX	UNIT		
VIK	$V_{CC} = 4.75,$	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2	V
Voн	$V_{CC} = 4.75,$	I _{OH} = -15 mA		2.4	3.3		V
v_{OL}	V _{CC} = 4.75,	I _{OL} = 12 mA			0.3	0.55	V
R _{out}	$V_{CC} = 4.75,$	I_{OL} = 12 mA		20	25	40	Ω
V_{hys}	All inputs				0.2		V
lį	V _{CC} = 5.25 V,	VIN = VCC				5	μΑ
lн	V _{CC} = 5.25 V,	V _{IN} = 2.7 V				±1	μΑ
IĮL	$V_{CC} = 5.25 \text{ V},$	V _{IN} = 0.5 V				±1	μΑ
lozh	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 2.7 V				10	μΑ
I _{OZL}	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 0.5 V				-10	μΑ
los [‡]	V _{CC} = 5.25 V,	VOUT = 0 V		-60	-120	-225	mA
l _{off}	$V_{CC} = 0 V$,	V _{OUT} = 4.5 V				±1	μΑ
lcc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
∆ICC	V _{CC} = 5.25 V, V _{IN} =	3.4 V\$, f ₁ = 0, Outputs op	oen		0.5	2	mA
I _{CCD} ¶		nput switching at 50% duty $N \le 0.2 \text{ V or V}_{IN} \ge \text{V}_{CC}$ –			0.06	0.12	mA/ MHz
		One input switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	0.7 1.4	
ı ₋ #	$V_{CC} = 5.25 \text{ V},$ Outputs open, $T/R = \overline{OE} = GND$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4	mA
lC#		Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.3	2.6	IIIA
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		3.3	10.6	
C _i					5	10	pF
Co					9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

I_C = Total supply current

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

 \parallel Values for these conditions are examples of the I_{CC} formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

 $[\]$ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

 $[\]P$ This parameter is derived for use in total power-supply calculations.

[#] I_{C} = I_{CC} + ΔI_{CC} × D_H × N_T + I_{CCD} ($f_0/2 + f_1$ × N_1)
Where:

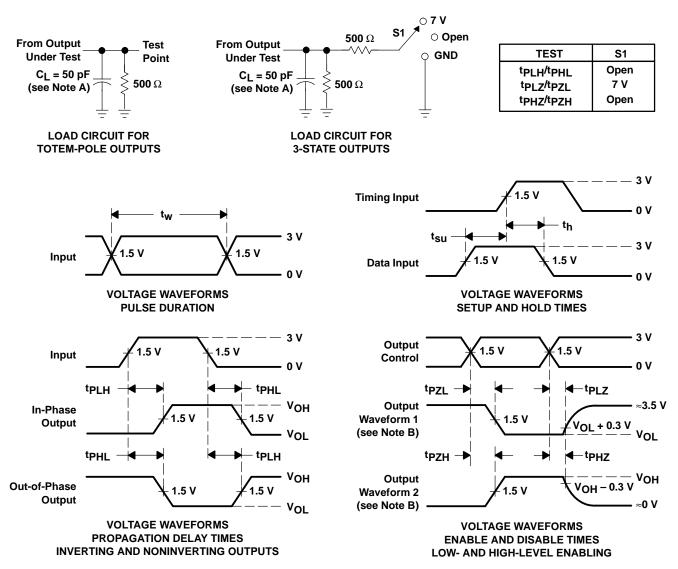
CY74FCT2245T **8-BIT TRANSCEIVER** WITH 3-STATE OUTPUTS SCCS037B – JULY 1994 – REVISED NOVEMBER 2001

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FCT2245T		CY74FCT2245AT		CY74FCT2245CT		UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B _n or A _n	1.5	7	1.5	4.6	1.5	4.1	ns
^t PHL	A _n or B _n		1.5	7	1.5	4.6	1.5	4.1	115
^t PZH	ŌĒ	A or B	1.5	9.5	1.5	6.2	1.5	5.8	20
t _{PZL}	OE		1.5	9.5	1.5	6.2	1.5	5.8	ns
^t PHZ	ŌĒ	A or B	1.5	7.5	1.5	5	1.5	4.5	20
tPLZ	OE .		1.5	7.5	1.5	5	1.5	4.5	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74FCT2245ATSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2245CTSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATPC	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT2245ATPCE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT2245ATPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245ATSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245CTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245CTSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245CTSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245CTSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245TQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT2245TSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{^{(1)}}$ The marketing status values are defined as follows:



PACKAGE OPTION ADDENDUM

6-Dec-2006

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



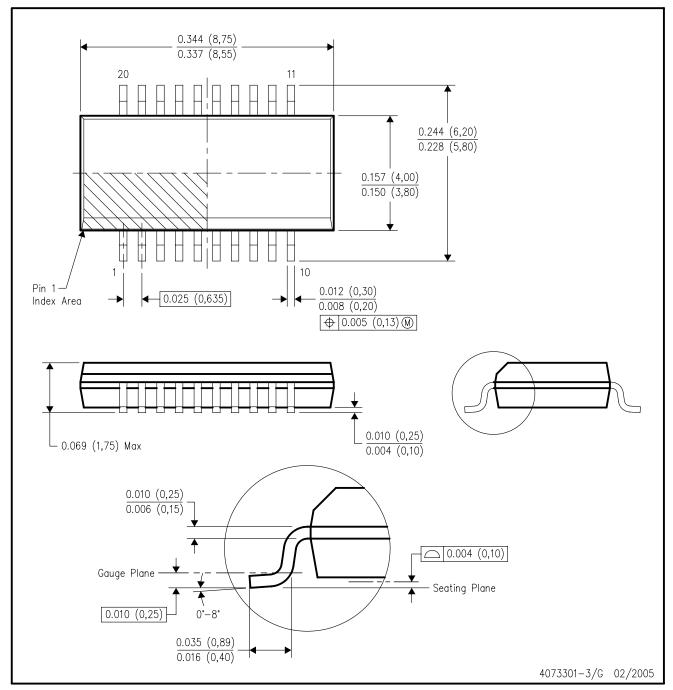
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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